

Vishay Semiconductors

Silicon NPN Phototransistor



DESCRIPTION

VEMT2500X01 series are silicon NPN epitaxial planar phototransistors in a miniature dome lens, clear epoxy package for surface mounting. The device is sensitive to visible and near infrared radiation.

FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- AEC-Q101 qualified
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\phi = \pm 15^{\circ}$
- Package matched with IR emitter series VSMB2000X01
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

APPLICATIONS

- Detector in automotive applications
- Photo interrupters
- Miniature switches
- Counters
- Encoders
- Position sensors

PRODUCT SUMMARY			
COMPONENT	I _{ca} (mA)	φ (deg)	λ _{0.1} (nm)
VEMT2500X01	6	± 15	470 to 1090
VEMT2520X01	6	± 15	470 to 1090

Note

· Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	ING CODE PACKAGING REMARKS P		PACKAGE FORM	
VEMT2500X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VEMT2520X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Collector emitter voltage		V _{CEO}	20	V	
Emitter collector voltage		V _{ECO}	7	V	
Collector current		Ι _C	50	mA	
Power power dissipation	$T_{amb} \le 75 \ ^{\circ}C$	P _V	100	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	



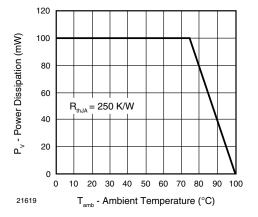


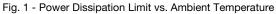
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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL VAL		UNIT	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	Acc. reflow profile fig. 8	T _{sd}	260	°C	
Thermal resistance junction/ambient	Acc. J-STD-051	R _{thJA}	250	K/W	



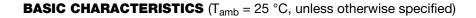


BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I _C = 0.1 mA	V _{CEO}	20			V
Collector dark current	$V_{CE} = 5 V, E = 0$	I _{CEO}		1	100	nA
Collector emitter capacitance	$V_{CE} = 0 V, f = 1 MHz, E = 0$	C _{CEO}		25		pF
Collector light current	$\begin{array}{l} E_{e} = 1 \ mW/cm^2, \lambda = 950 \ nm, \\ V_{CE} = 5 \ V \end{array}$	I _{CA}	3	6	9	mA
Angle of half sensitivity		φ		± 15		deg
Wavelength of peak sensitivity		λp		850		nm
Range of spectral bandwidth		λ _{0.1}		470 to 1090		nm
Collector emitter saturation voltage	I _C = 0.05 mA	V _{CEsat}			0.4	V
Temperature coefficient of Ica	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \\ V_{CE} = 5 \text{ V}$	Tk _{ica}		1.1		%/K



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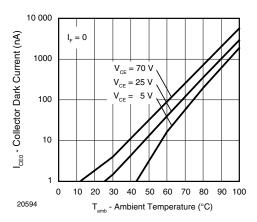


Fig. 2 - Collector Dark Current vs. Ambient Temperature

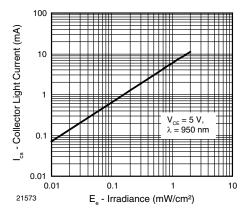


Fig. 3 - Collector Light Current vs. Irradiance

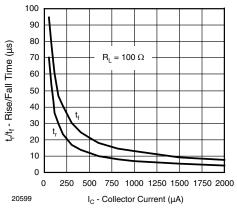


Fig. 4 - Rise/Fall Time vs. Collector Current

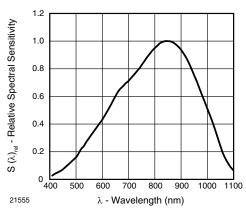


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

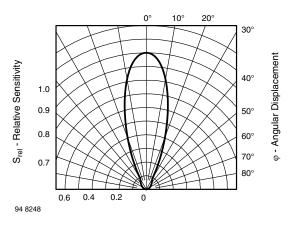


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

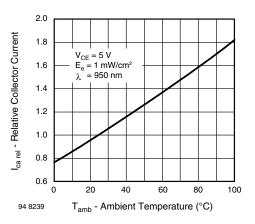


Fig. 7 - Relative Collector Current vs. Ambient Temperature

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REFLOW SOLDER PROFILE

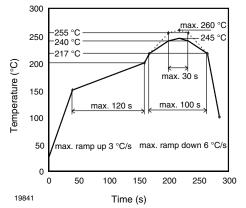
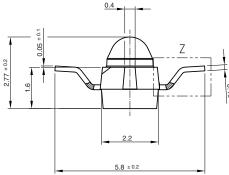
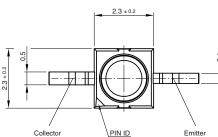
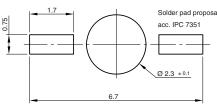


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

PACKAGE DIMENSIONS VEMT2500X01 in millimeters







Drawing-No.: 6.544-5391.01-4 Issue: 1; 26.09.08 21570



Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

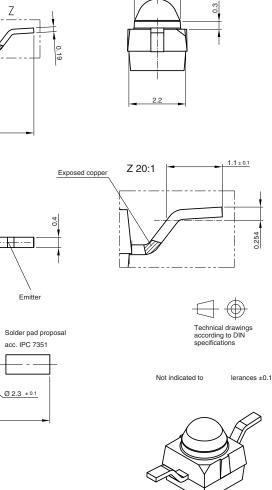
FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 4 weeks Conditions: $T_{amb} < 30$ °C, RH < 60 % Moisture sensitivity level 2a, acc. to J-STD-020.

DRYING

Ø 1.8 ± 0.1

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

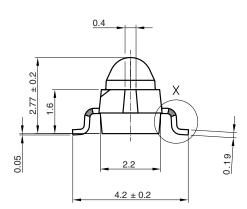


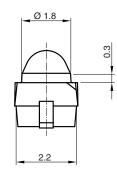


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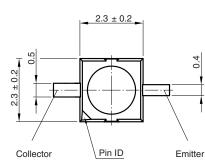
PACKAGE DIMENSIONS VEMT2520X01 in millimeters

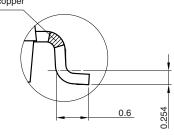




Exposed copper

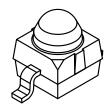
X 20:1

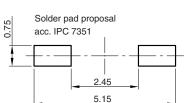






Not indicated tolerances ± 0.1





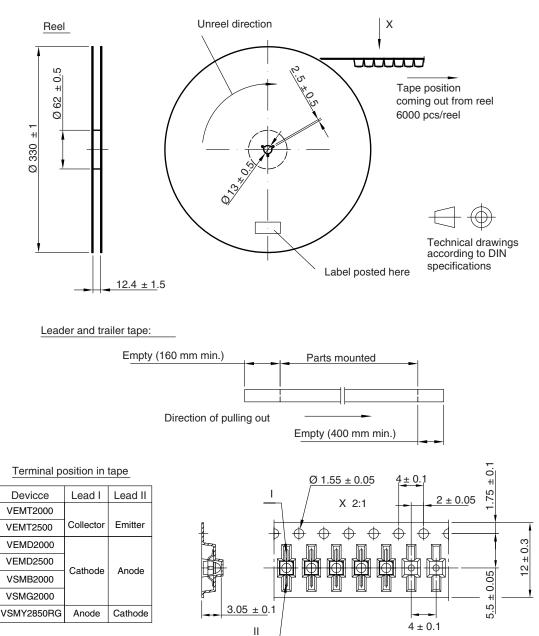
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TAPE AND REEL DIMENSIONS VEMT2500X01 in millimeters



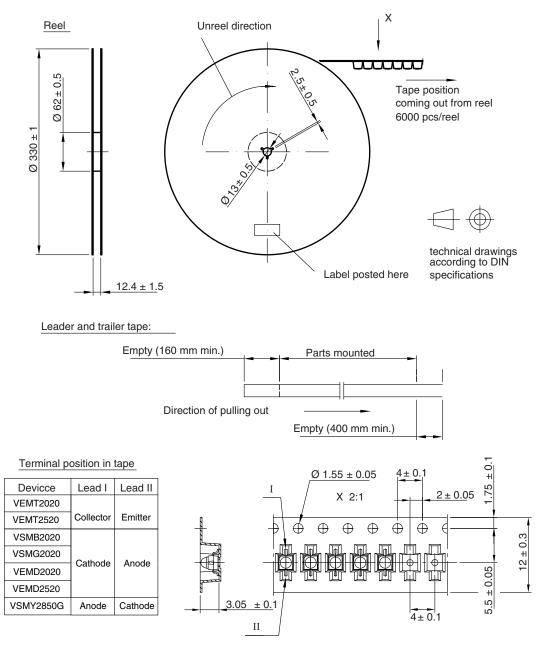
Drawing-No.: 9.800-5100.01-4 Issue: 2; 18.03.10 21572



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TAPE AND REEL DIMENSIONS VEMT2520X01 in millimeters



Drawing-No.: 9.800-5091.01-4 Issue: 3; 18.03.09 21571



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